Attorney Reference		

DECLARATION FOR UNITED STATES PATENT APPLICATION, POWER OF ATTORNEY, DESIGNATION OF CORRESPONDENCE ADDRESS

As a below named inventor, I hereby d clare that my residence, post offic address and citizenship ar as stated below next to my name, and that I believ I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are list d below) of the subject matter which is claim d and for which a patent is sought on the inventor entitled

COMBINED SEMICONDUCTOR APPARATUS WITH SEMICONDUCTOR THIN FILM						
the specification of which	·			······································		
[X] is attached hereto. [] was filed on and was amended on [] was filed under the Paten Serial No	t Cooperation Treaty on, the United			,		
I hereby state that I have revi- I acknowledge the duty to dis- patentability as defined in Titl	ewed and understand the c close to the Patent and Tra	ontents of the above-ide demark Office information	ntified specification			
I hereby claim foreign prinv ntor's certificate listed be filing date before that of the a Prior Foreign Application(s)	low and have also identified	d below any foreign appli	§119 of any foreig cation for patent or	gn application(s) for patent or inventor's certificate having a		
Date Filed	Number	Priority Claime Yes No	ed	Country		
Date Filed	Number	165 140		Country		
December 24, 2002	2002-371724	x		JAPAN		
Address all correspo		*23995* 23995 atent Trademark Office				
assignee, if any, and/or, if the attorney, patent agent, or parent	authorizes the U.S. attorne e undersigned is not a res tent representative as to a munication between the U.S	ys named herein to accesident of the United Statent of the United Staten in action to be taken in attorneys and the unde	tes, the undersigne the Patent and Tra ersigned. In the eve	actions from the undersigned's d's domestic attorney, patent ademark Office regarding this nt of a change in the person(s) dersigned.		
belief are believed to be true;	and further that these state y fine or imprisonment, or b	ments were made with the oth, under §1001 of Title	ne knowledge that v 18 of the United Sta	nents made on information and villful false statements and the ates Code and that such willful		
Signature: MHSG First Joint Inventor: Mitsuhiko Citiz nship: Japan			ecember 5	, 2003.		
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